# 1PS79SB30

# Schottky barrier single diode

24 July 2012

**Product data sheet** 

# 1. Product profile

## 1.1 General description

Planar Schottky barrier diode with an integrated guard ring for stress protection, encapsulated in a SOD523 (SC-79) ultra small Surface-Mounted Device (SMD) plastic package.

#### 1.2 Features and benefits

- Very low forward voltage
- Very low reverse current
- Guard ring protected
- Ultra small SMD package
- AEC-Q101 qualified

## 1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Blocking diodes

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>F</sub>	forward current		-	-	200	mA
V <sub>R</sub>	reverse voltage		-	-	40	V
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 10 mA; T <sub>amb</sub> = 25 °C	-	320	360	mV

# 2. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode[1]	1 2	к <b>-}</b> А
2	A	anode	SOD523	aaa-003679

<sup>[1]</sup> The marking bar indicates the cathode.





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# 3. Ordering information

#### Table 3. Ordering information

Type number	Package	age				
	Name	Description	Version			
1PS79SB30	SOD523	plastic surface-mounted package; 2 leads	SOD523			

# 4. Marking

#### Table 4. Marking codes

Type number	Marking code
1PS79SB30	G1

# 5. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_R$	reverse voltage		-	40	V
I <sub>F</sub>	forward current		-	200	mA
I <sub>FRM</sub>	repetitive peak forward current	$t_p \le 1 \text{ s}; \ \delta \le 0.5$	-	300	mA
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; half sine wave	-	1	А
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	150	°C
T <sub>stg</sub>	storage temperature		-65	150	°C

# 6. Thermal characteristics

#### Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	-	450	K/W

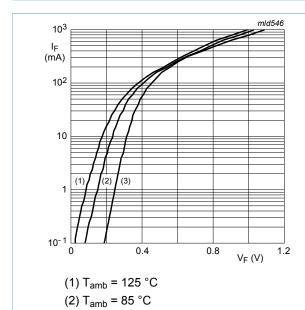
<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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# 7. Characteristics

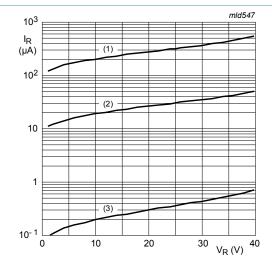
Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 0.1 mA; T <sub>amb</sub> = 25 °C	-	190	220	mV
		I <sub>F</sub> = 1 mA; T <sub>amb</sub> = 25 °C	-	250	290	mV
		I <sub>F</sub> = 10 mA; T <sub>amb</sub> = 25 °C	-	320	360	mV
		I <sub>F</sub> = 100 mA; T <sub>amb</sub> = 25 °C	-	440	500	mV
		I <sub>F</sub> = 200 mA; T <sub>amb</sub> = 25 °C	-	520	600	mV
I <sub>R</sub>	reverse current	$V_R$ = 25 V; $T_{amb}$ = 25 °C; pulsed; $t_p$ = 300 µs; $\delta$ = 0.02	-	-	0.5	μΑ
C <sub>d</sub>	diode capacitance	f = 1 MHz; T <sub>amb</sub> = 25 °C; V <sub>R</sub> = 1 V	-	-	20	pF



(3)  $T_{amb}$  = 25 °C Fig. 1. Forward current as a function of forward

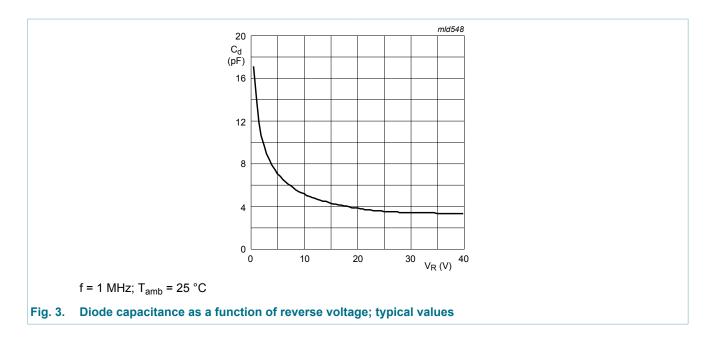
voltage; typical values



- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb}$  = 85 °C
- (3)  $T_{amb}$  = 25 °C

Fig. 2. Reverse current as a function of reverse voltage; typical values

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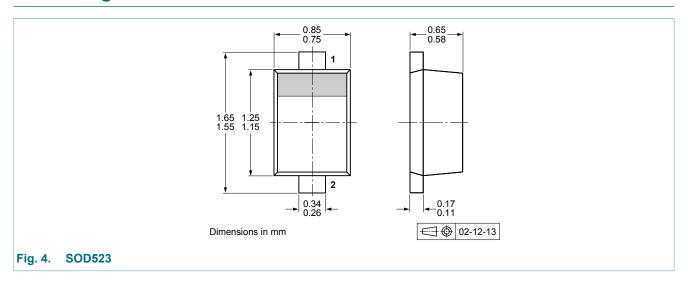


# 8. Test information

# 8.1 Quality information

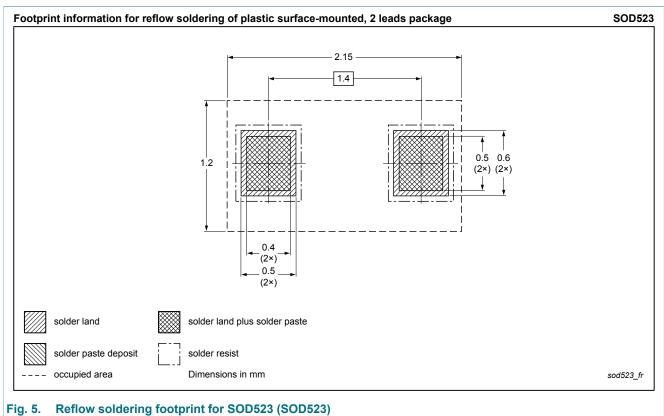
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

# 9. Package outline



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# 10. Soldering



# 11. Revision history

Table 8. **Revision history** 

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
1PS79SB30 v.2	20120724	Product data sheet	-	1PS79SB30 v.1
Modifications:	of NXP Semiconduct Legal texts have be Section "Product product prod	ctors. en adapted to the new co ofile" updated dded wing replaced by minimiz nation" added	igned to comply with the ompany name where app	ropriate.
1PS79SB30 v.1	20010220	Product data sheet	-	-

#### Schottky barrier single diode

# 12. Legal information

#### 12.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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